

ADJUSTABLE PRECISION SHUNT REGULATORS

AZ431-B

Pin Configuration

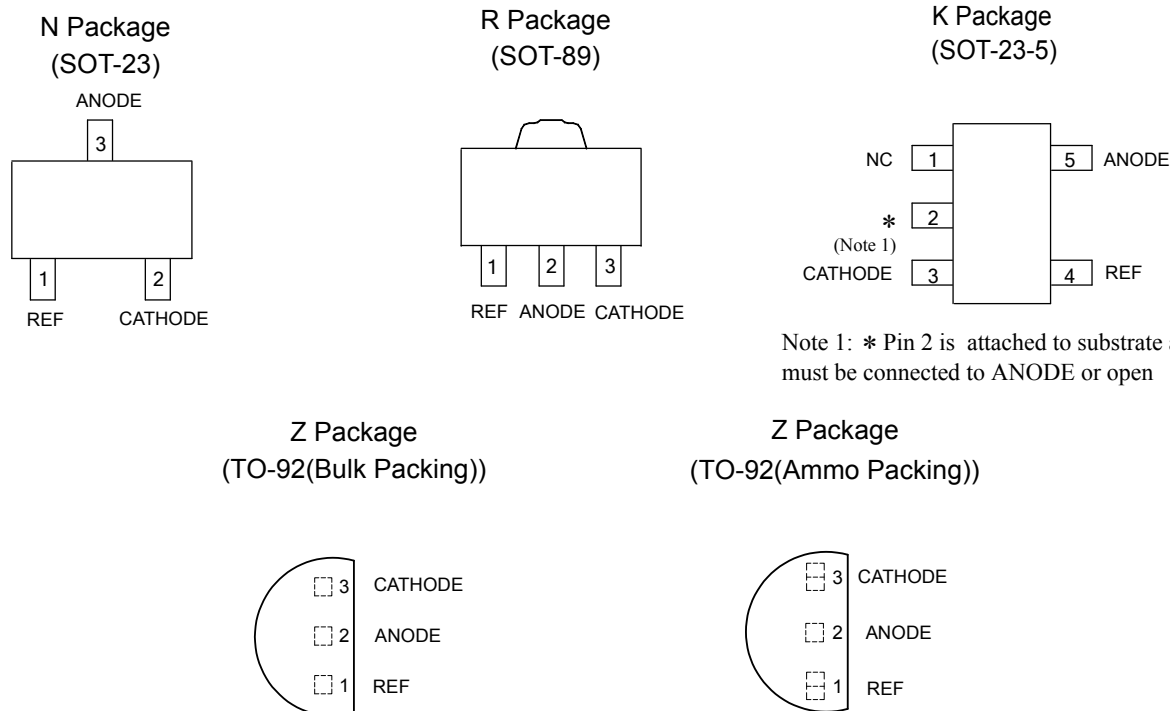


Figure 2. Pin Configuration of AZ431-B (Top View)

Functional Block Diagram

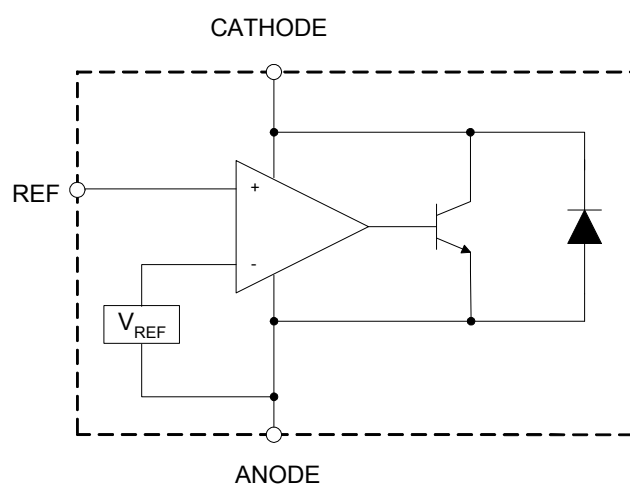
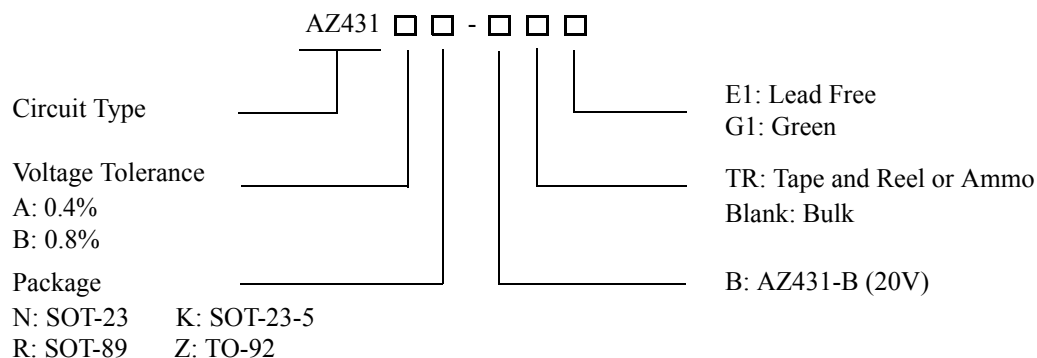


Figure 3. Functional Block Diagram of AZ431-B

ADJUSTABLE PRECISION SHUNT REGULATORS

AZ431-B

Ordering Information



Package	Temperature Range	Voltage Tolerance	Part Number		Marking ID		Packing Type
			Lead Free	Green	Lead Free	Green	
SOT-23	-40 to 125°C	0.4%	AZ431AN-BTRE1	AZ431AN-BTRG1	EA4	GA4	Tape & Reel
		0.8%	AZ431BN-BTRE1	AZ431BN-BTRG1	EA5	GA5	Tape & Reel
SOT-23-5	-40 to 125°C	0.4%	AZ431AK-BTRE1	AZ431AK-BTRG1	E4A	G4A	Tape & Reel
		0.8%	AZ431BK-BTRE1	AZ431BK-BTRG1	E4B	G4B	Tape & Reel
TO-92	-40 to 125°C	0.4%	AZ431AZ-BE1	AZ431AZ-BG1	AZ431AZ-BE1	AZ431AZ-BG1	Bulk
		0.4%	AZ431AZ-BTRE1	AZ431AZ-BTRG1	AZ431AZ-BE1	AZ431AZ-BG1	Ammo
		0.8%	AZ431BZ-BE1	AZ431BZ-BG1	AZ431BZ-BE1	AZ431BZ-BG1	Bulk
		0.8%	AZ431BZ-BTRE1	AZ431BZ-BTRG1	AZ431BZ-BE1	AZ431BZ-BG1	Ammo
SOT-89	-40 to 125°C	0.4%	AZ431AR-BTRE1	AZ431AR-BTRG1	E43C	G43C	Tape & Reel
		0.8%	AZ431BR-BTRE1	AZ431BR-BTRG1	E43D	G43D	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Absolute Maximum Ratings (Note 2)**

Parameter	Symbol	Value	Unit
Cathode Voltage	V_{KA}	20	V
Cathode Current Range (Continuous)	I_{KA}	-100 to 150	mA
Reference Input Current Range	I_{REF}	10	mA
Power Dissipation	P_D	Z, R Package: 770	mW
		N, K Package: 370	
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-65 to 150	°C
ESD (Human Body Model)	ESD	2000	V

Note 2: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Cathode Voltage	V_{KA}	V_{REF}	18	V
Cathode Current	I_{KA}	1.0	100	mA
Operating Ambient Temperature Range	T_A	-40	125	°C



ADJUSTABLE PRECISION SHUNT REGULATORS

AZ431-B

Electrical Characteristics

Operating Conditions: $T_A=25^{\circ}\text{C}$, unless otherwise specified.

Parameter	Test Circuit	Symbol	Conditions	Min	Typ	Max	Unit
Reference Voltage	0.4%	4	$V_{KA}=V_{REF}, I_{KA}=10\text{mA}$	2.490	2.500	2.510	V
	0.8%			2.480	2.500	2.520	
Deviation of Reference Voltage Over Full Temperature Range	4	ΔV_{REF}	$V_{KA}=V_{REF}$ $I_{KA}=10\text{mA}$	0 to 70°C	4.5	8	mV
				-40 to 85°C	4.5	10	
				-40 to 125°C	4.5	16	
Ratio of Change in Reference Voltage to the Change in Cathode Voltage	5	$\frac{\Delta V_{REF}}{\Delta V_{KA}}$	$I_{KA}=10\text{mA}$	$\Delta V_{KA}=10\text{V}$ to V_{REF}	-1.0	-2.7	mV/V
				$\Delta V_{KA}=18\text{V}$ to 10V	-0.5	-2.0	
Reference Current	5	I_{REF}	$I_{KA}=10\text{mA}, R1=10\text{K}\Omega, R2=\infty$		0.7	4	μA
Deviation of Reference Current Over Full Temperature Range	5	ΔI_{REF}	$I_{KA}=10\text{mA}, R1=10\text{K}\Omega, R2=\infty$ $T_A=-40$ to 125°C		0.4	1.2	μA
Minimum Cathode Current for Regulation	4	$I_{KA}(\text{Min})$	$V_{KA}=V_{REF}$		0.4	1.0	mA
Off-state Cathode Current	6	$I_{KA}(\text{Off})$	$V_{KA}=18\text{V}, V_{REF}=0$		0.05	1.0	μA
Dynamic Impedance	4	Z_{KA}	$V_{KA}=V_{REF}, I_{KA}=1$ to 100mA $f \leq 1.0\text{KHz}$		0.2	0.5	Ω
Thermal Resistance		θ_{JC}	SOT-23		177.65		$^{\circ}\text{C/W}$
			SOT-23-5		177.65		
			TO-92		107.04		
			SOT-89		30.30		

ADJUSTABLE PRECISION SHUNT REGULATORS

AZ431-B

Electrical Characteristics (Continued)

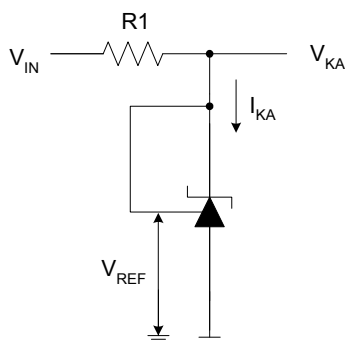


Figure 4. Test Circuit 4 for $V_{KA}=V_{REF}$

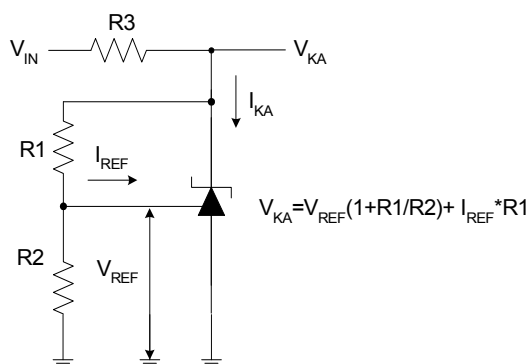


Figure 5. Test Circuit 5 for $V_{KA}>V_{REF}$

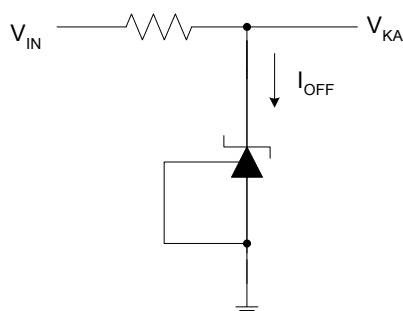


Figure 6. Test Circuit 6 for I_{OFF}

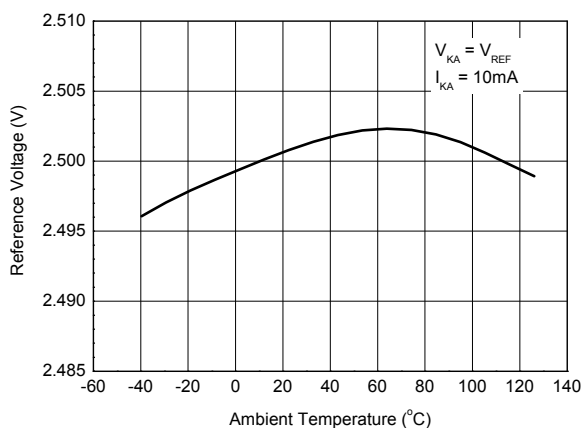
**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Typical Performance Characteristics**

Figure 7. Reference Voltage vs. Ambient Temperature

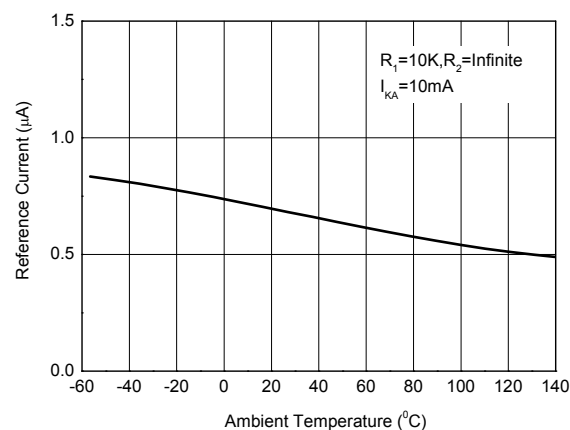


Figure 8. Reference Current vs. Ambient Temperature

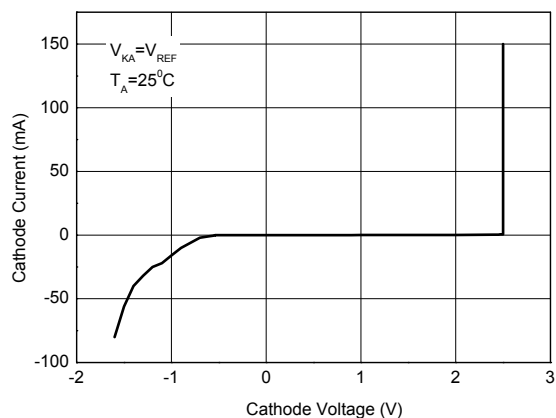


Figure 9. Cathode Current vs. Cathode Voltage

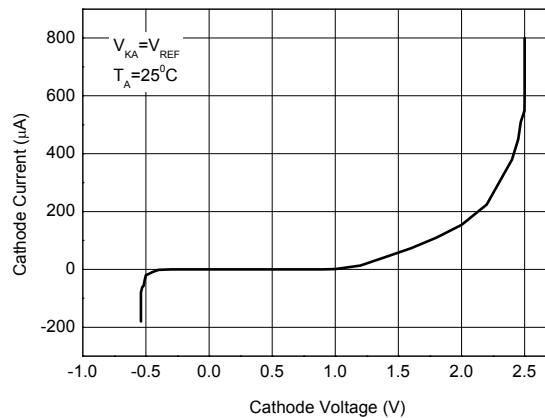


Figure 10. Cathode Current vs. Cathode Voltage

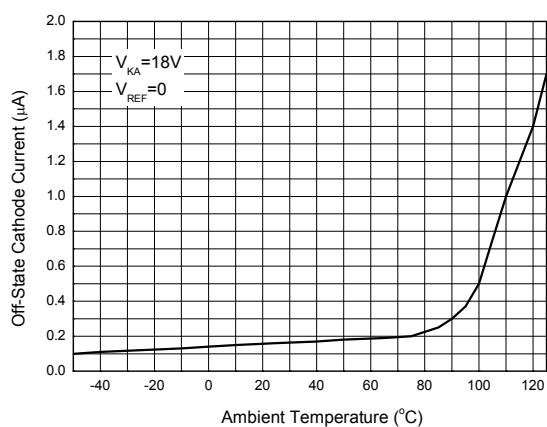
**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Typical Performance Characteristics (Continued)**

Figure 11. Off-State Cathode Current vs. Ambient Temperature

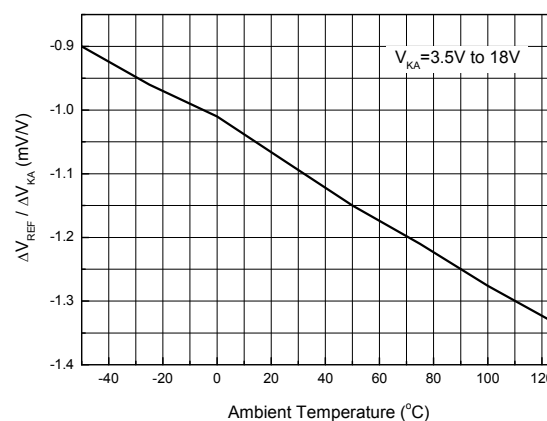


Figure 12. Ratio of Delta Reference Voltage to the Ratio of Delta Cathode Voltage

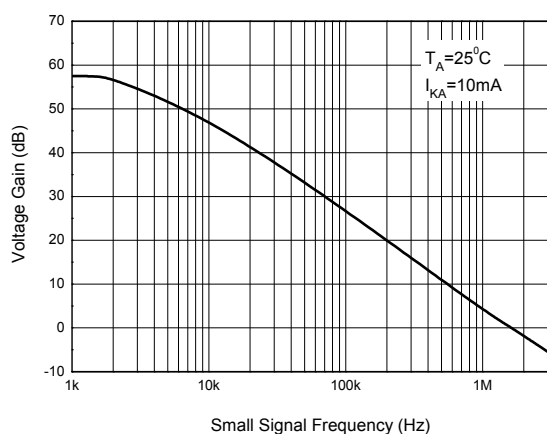
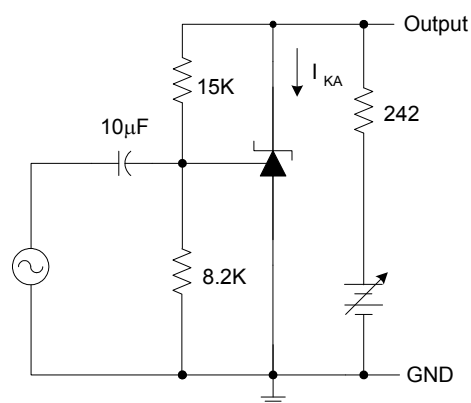


Figure 13. Small Signal Voltage Gain vs. Frequency



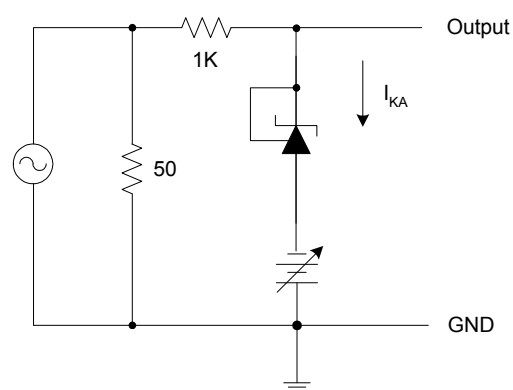
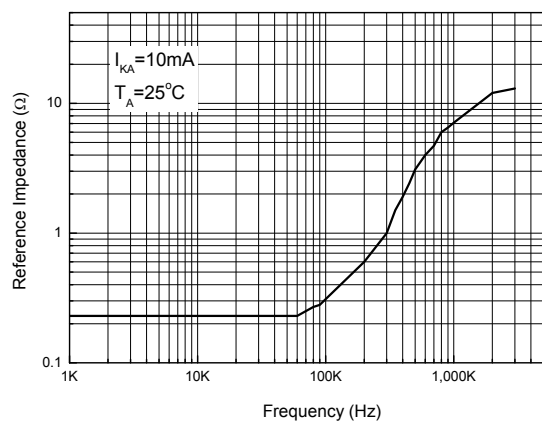
**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Typical Performance Characteristics (Continued)**

Figure 14. Reference Impedance vs. Frequency

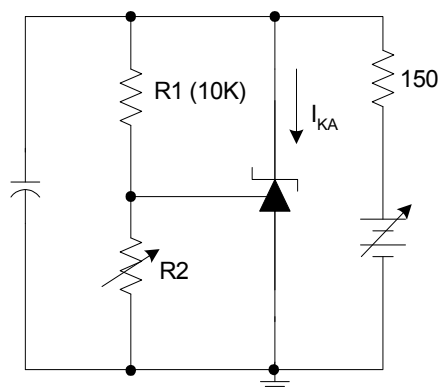
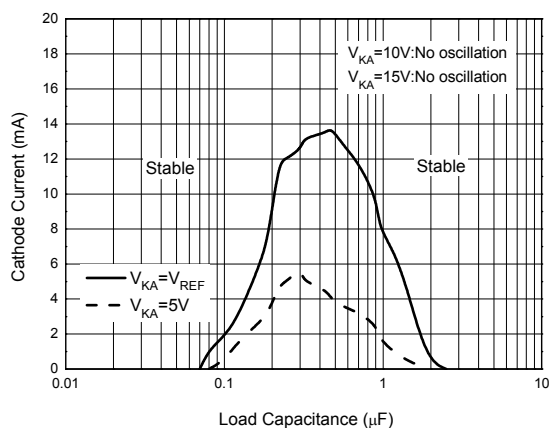


Figure 15. Stability Boundary Conditions vs. Load Capacitance

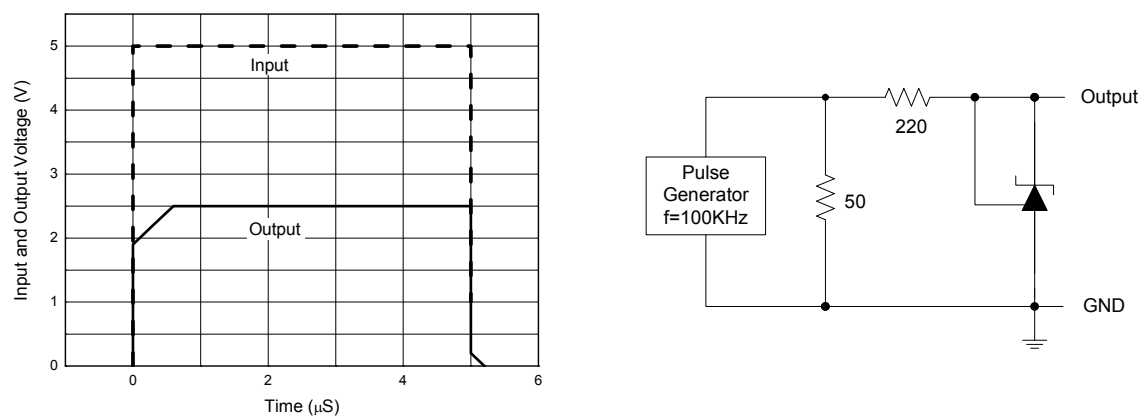
**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Typical Performance Characteristics (Continued)**

Figure 16. Pulse Response of Input and Output Voltage

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AZ431-B

Typical Application

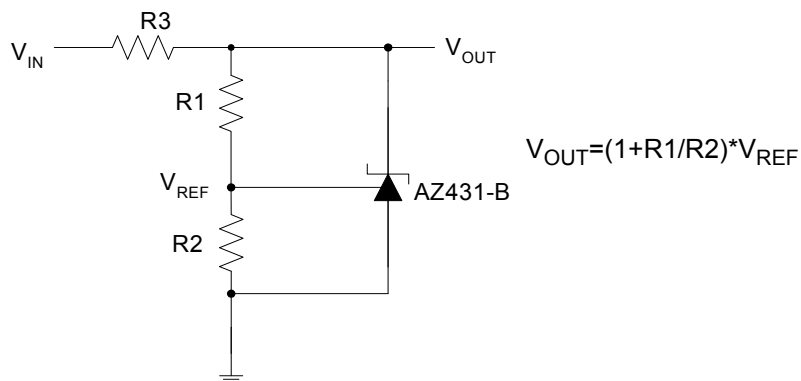


Figure 17. Shunt Regulator

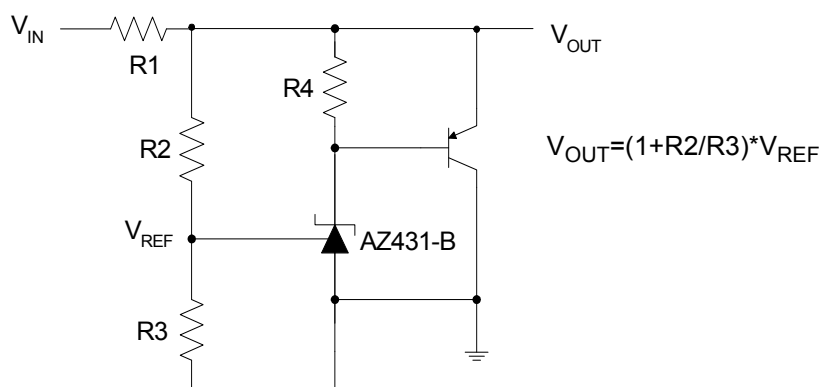


Figure 18. High Current Shunt Regulator

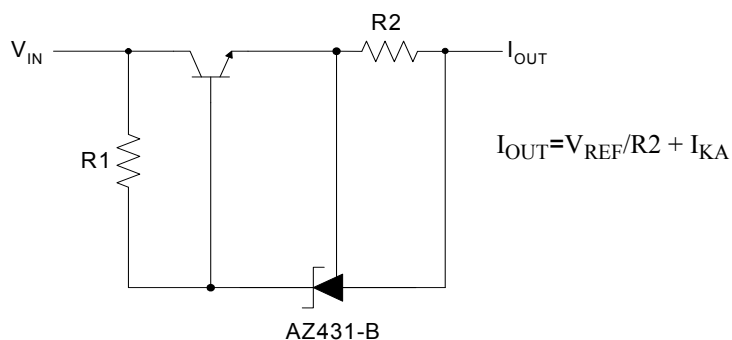
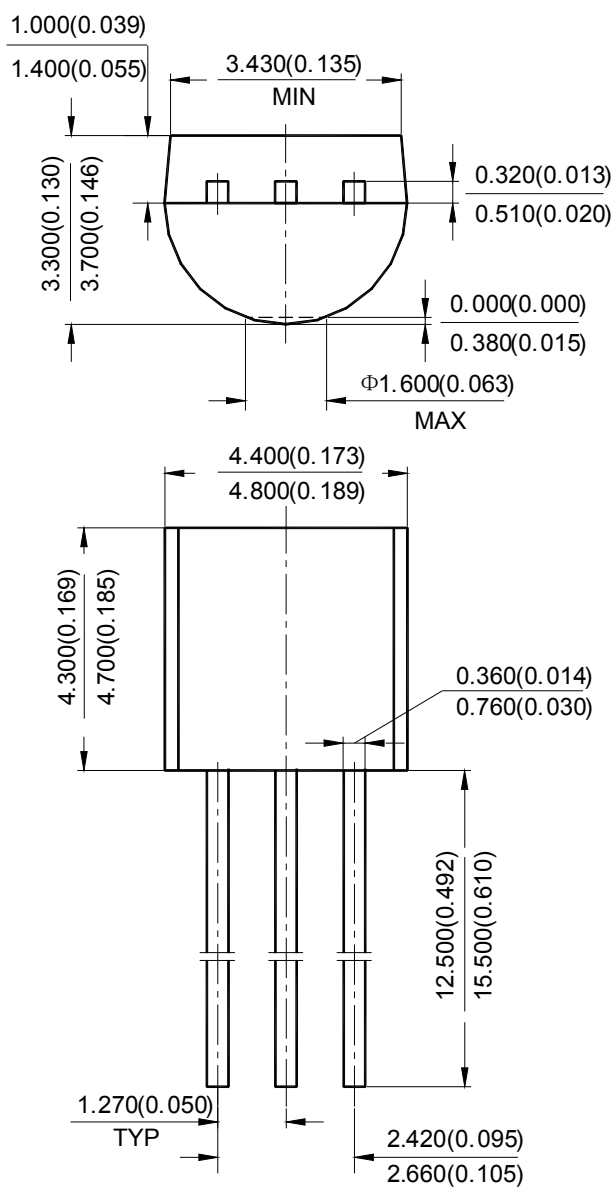


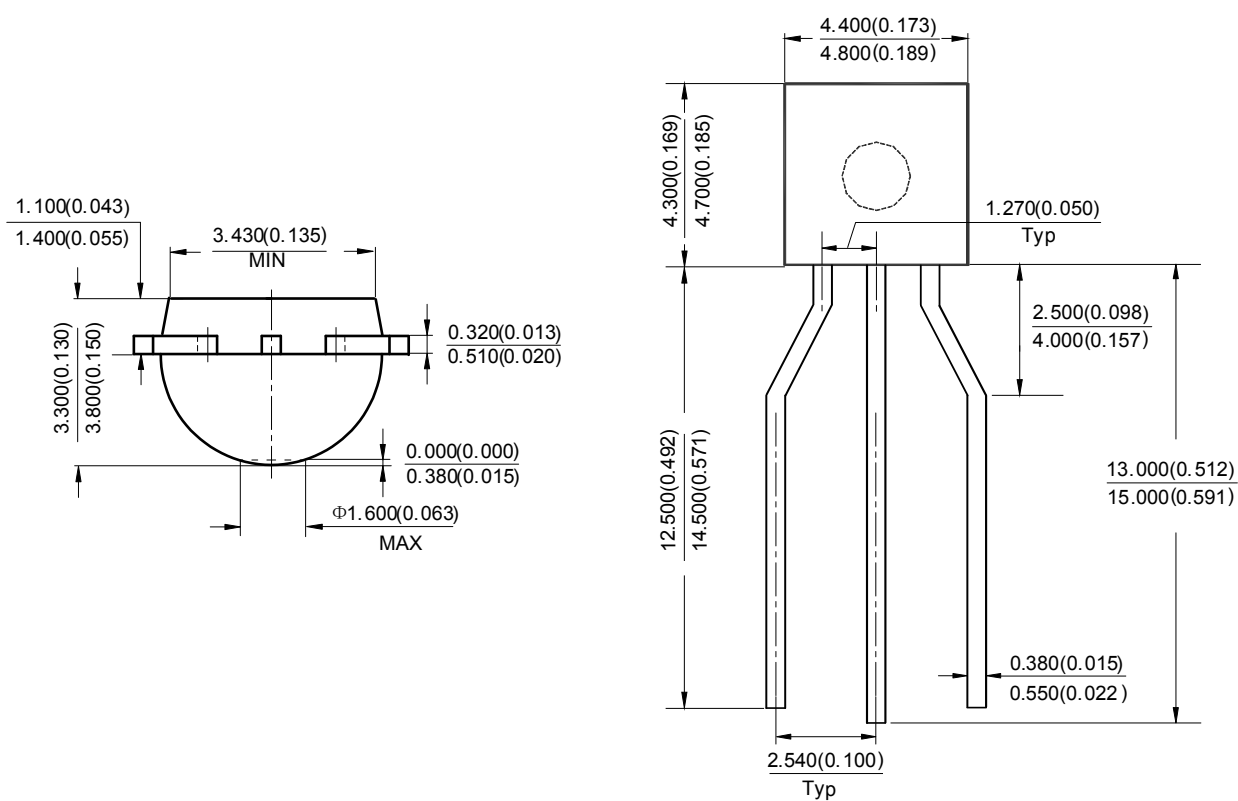
Figure 19. Current Source or Current Limit

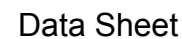
AZ431-B

Typical Application (Continued)



**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Mechanical Dimensions****TO-92(Bulk Packing)****Unit: mm(inch)**

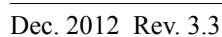
**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Mechanical Dimensions (Continued)****TO-92(Ammo Packing)****Unit: mm(inch)**



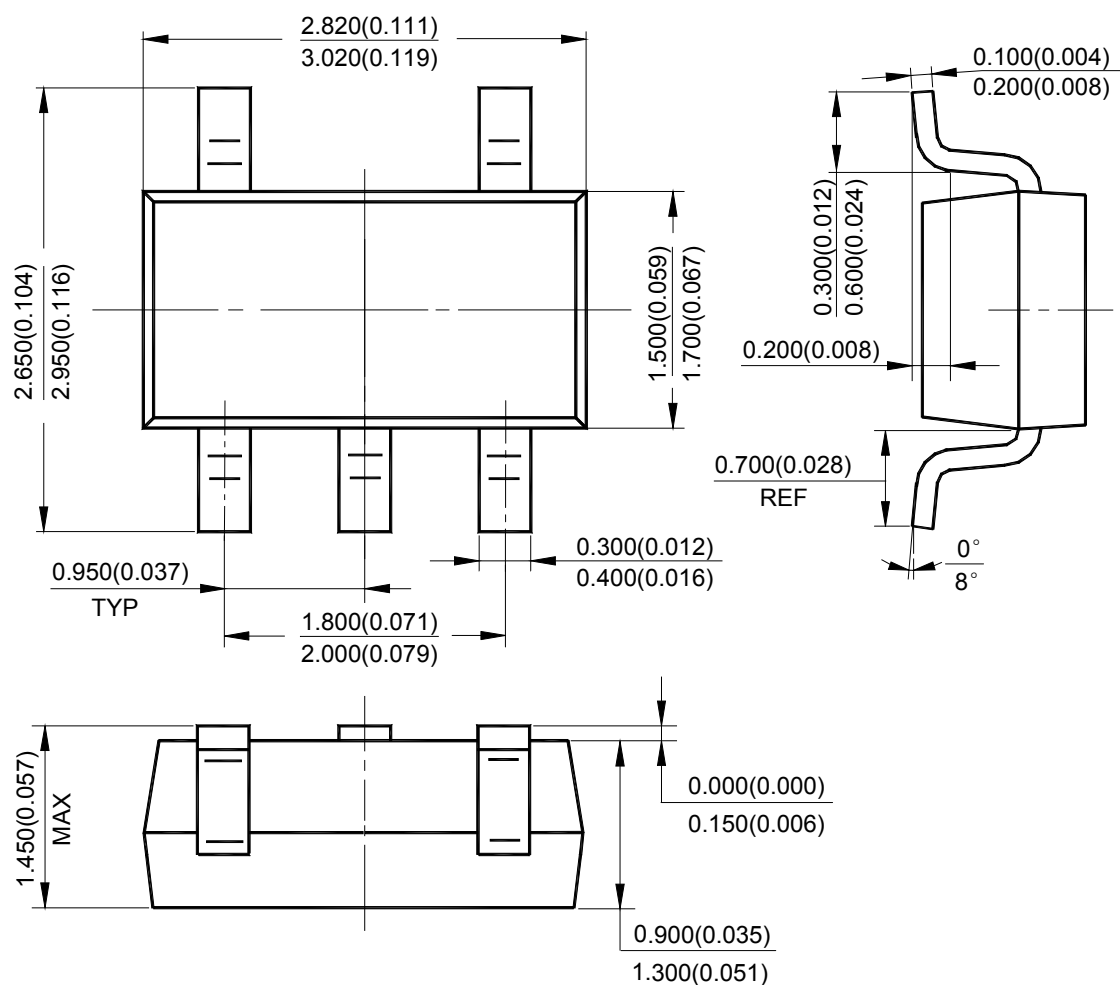
AZ431-B

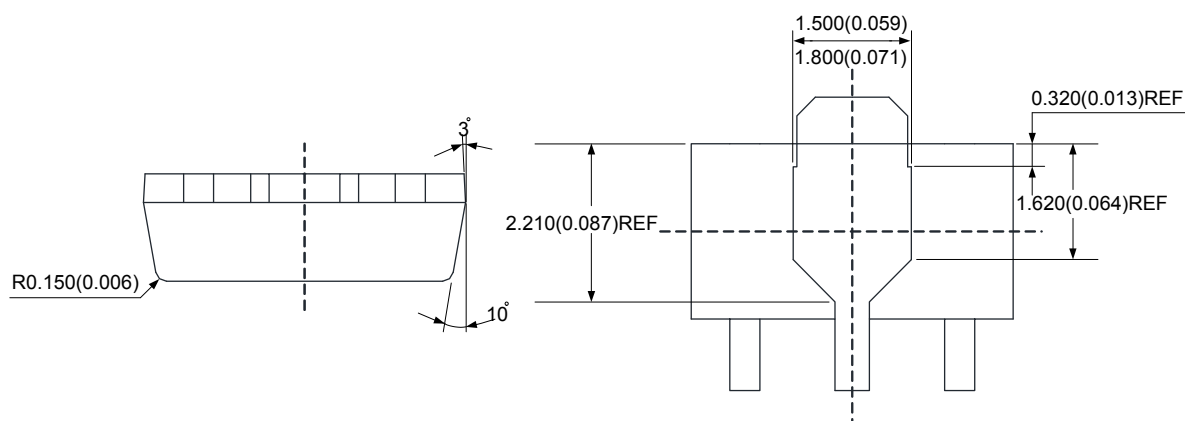
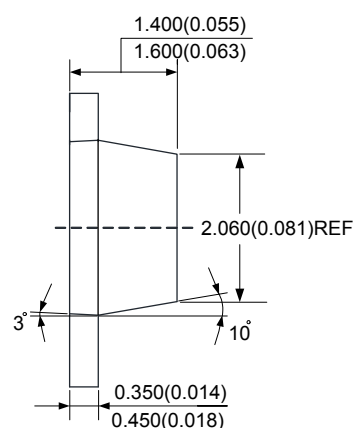
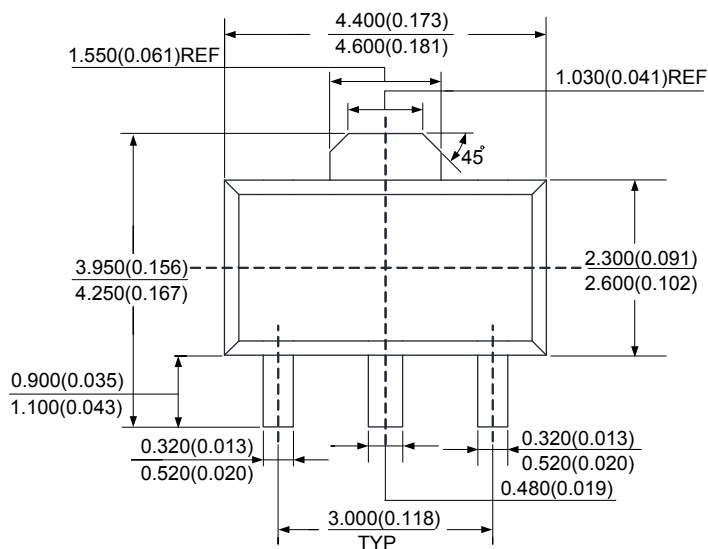
SOT-23

Unit: mm(inch)



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**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Mechanical Dimensions (Continued)****SOT-23-5****Unit: mm(inch)**

**ADJUSTABLE PRECISION SHUNT REGULATORS****AZ431-B****Mechanical Dimensions (Continued)****SOT-89****Unit: mm(inch)**



BCD Semiconductor Manufacturing Limited

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